



Complementary wireless module WLAN

Standard Laminate SiP Module

Series/Type:	R078 (WL1801) / D7021
Ordering code:	B30911D7021Y918
Date:	2014-09-25
Version:	1.2

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1 Overview

This document details the specifications and features of R078 (WL1801) / D7021 SiP module. The R078 (WL1801) / D7021 SiP module is based on Texas Instruments WL1801 IC, specifically WL180x Data Sheet version 1.2, such that the SiP module specification is subject to any subsequent changes in applicable Texas Instruments documentation and software.

The R078 (WL1801) / D7021 contains the WL1801 SoC, 2.4GHz SPDT switch, 2.4GHz band pass filter / diplexer and necessary passive components for WLAN in a highly integrated solution.

1.1 Features

- WLAN on a single chip provides universal connectivity in small PCB footprint.
- Provides efficient direct connection to battery by employing several integrated switched mode power supplies (DC2DC).
- Based on 45nm CMOS technology using proven core technology.
- Seamless integration with TI OMAP™ Application Processors.
- WLAN core software and hardware are compatible with prior WL127x and WL128x offerings, for smooth migration to Device.
- SDIO for WLAN.
- Downloadable patches and firmware enables new features to be added for all functional block's.
- Temperature detection and compensation mechanism ensures minimal variation in the RF performance over the entire temperature range.

1.2 Applications

Mobile phone and mobile computer device applications.

1.3 General Description

The R078 (WL1801) / D7021 is a highly integrated WLAN device that forms a complete standalone communication system. The WL1801 is a highly integrated single-chip CMOS (45-nm process) incorporates the core functionality of the WL1271/3 and WL1281/3 devices.

The device is the 8th-generation WLAN device from Texas Instruments. As such, the WL1801 is based upon proven core technology and complements the TI integrated devices for connectivity portfolio.

R078 (WL1801) / D7021 is ideal for use in mobile phone and mobile computer device applications due to its low current, small area and cellular phone coexistence-friendly features.

1.4 Terms and abbreviations

BPF – Band-Pass Filter

FE – Front-End (refers to FE IC and BPF)

GND – Ground

IC – Integrated Circuit

I/O – Input/Output interfaces

LDO – Low Drop-Out (voltage regulator)

PCB – Printed Circuit Board

Q – Quality factor

RF – Radio Frequency

RX – Receive

SiP – System in Package

SoC – System on Chip

TX – Transmit

Vbat – Battery Voltage

VIO – external pre-existing 1.8V IO power supply

WLAN – Wireless Local Area Network

1.5 Reference documents

- Texas Instruments WL180x_Data_Manual_Rev_1_2.pdf

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2 Functional Block Features

2.1 Functional Block Diagram

Figure 2-1 shows a high-level view of R078 (WL1801) / D7021 along with its various configurations. The flexibility of the R078 (WL1801) / D7021 based on WL1801 enables easy integration with various host-system topologies.

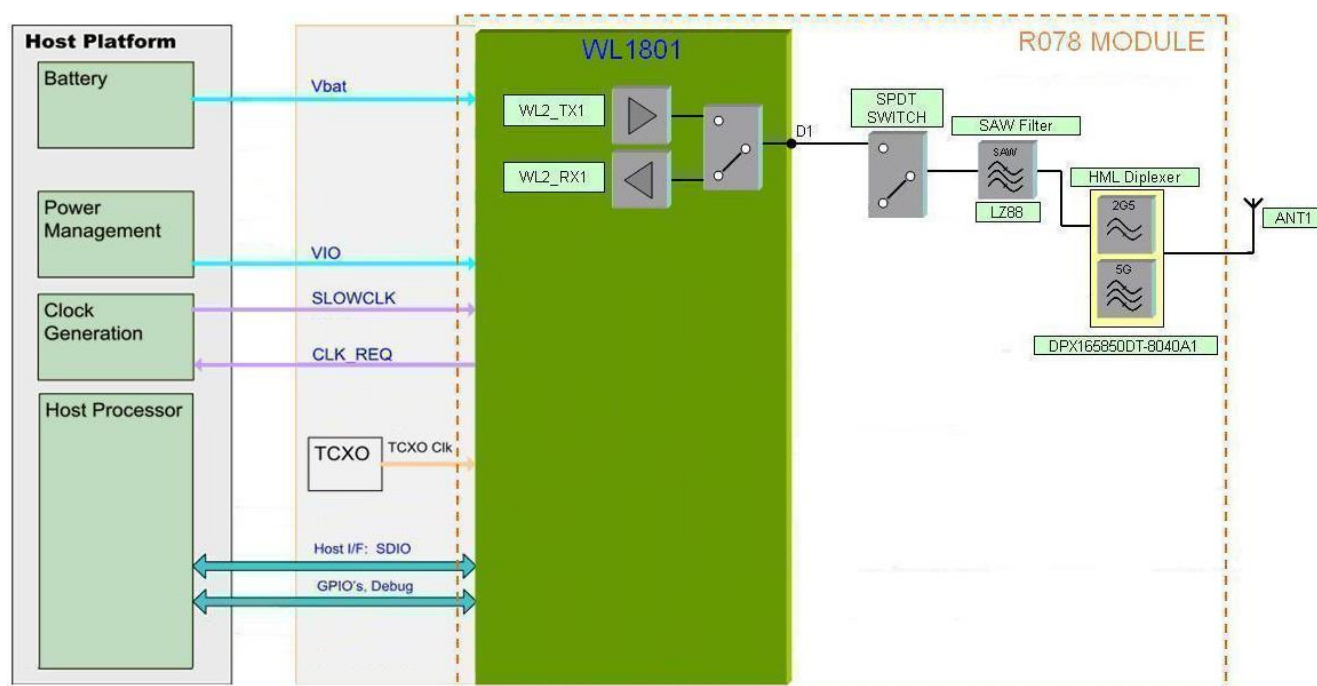


Figure 2-1 High-Level System Diagram

2.2 WLAN Features

- Integrated 2.4GHz power amplifiers for complete WLAN solution
- WLAN MAC Baseband Processor and RF transceiver - IEEE802.11b/g/n compliant
- WLAN 2.4GHz SISO (20 / 40 MHz channels).
- Baseband Processor
 - IEEE Std 802.11b/g data rates and IEEE Std 802.11n data rates with 20 or 40 MHz SISO.
- Fully calibrated system. No production calibration required.
- Medium-Access Controller (MAC)
 - Embedded ARM™ Central Processing Unit (CPU)
 - Hardware-Based Encryption/Decryption Using 64-, 128-, and 256-Bit WEP, TKIP or AES Keys,
 - Supports requirements for Wi-Fi Protected Access (WPA and WPA2.0) and IEEE Std 802.11i [Includes Hardware-Accelerated Advanced-Encryption Standard (AES)]
 - Designed to work with IEEE Std 802.1x
- 2.4GHz Radio
- Internal LNA, PA and RF switch
 - Supports: IEEE Std 802.11b, 802.11g and 802.11n
 - Supports 4 bit SDIO host interface, including high speed (HS) and V3 modes

3 Detailed Description

3.1 Host Interfaces

3.1.1 WLAN SDIO Transport Layer

The SDIO is the host interface for WLAN. The interface between the host and the D7021 uses an SDIO interface and supports a maximum clock rate of 50MHz.

The Device SDIO also supports the following features of the SDIO V3 specification:

- 4 bit data bus
- Synchronous and Asynchronous In-Band-Interrupt
- Default and High-Speed (50MHz) timing
- Sleep/wake commands

SDIO timing specifications are given in specification section at end of document.

3.2 Clocks and Power Management

3.2.1 Slow Clock / RTC clock

The slow clock is a free-running clock of 32.768 KHz which is supplied from an external clock source. It is connected to the RTC_CLK pin and is a digital square-wave signal in the range of 0-1.8V nom.

3.2.2 Fast Clock System

3.2.2.1 Fast clock using external crystal

The devices incorporate an internal crystal oscillator circuit for supporting a cost optimized crystal based fast clock scheme. Connection is as shown:

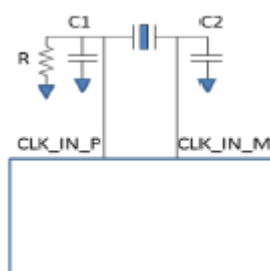


Figure 3-1 XTAL Connection

C1 = C2. Typically 8 - 22pF. Refer to Crystal manufacturer's recommendations.

R = 390K ohm (+/- 5% tolerance).

3.2.2.2 Fast Clock using external oscillator

CLK_IN_P is the main system fast clock and must meet the specifications as described in "Fast clock specifications" at the end of this document.

The clock must be one of the specified frequencies and the device incorporates an internal mechanism to detect this. The clock can be AC or DC coupled, sine or square wave.

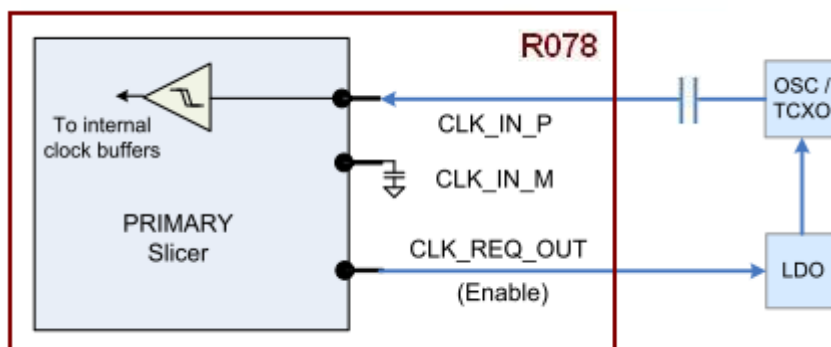


Figure 3-2 Fast Clock Block Diagram

3.2.3 Power Management

3.2.3.1 Block Diagram - internal DC2DC's

The Device incorporates three internal DC2DC's (switched-mode power supplies) to provide efficient internal and external supplies, derived from Vbat.

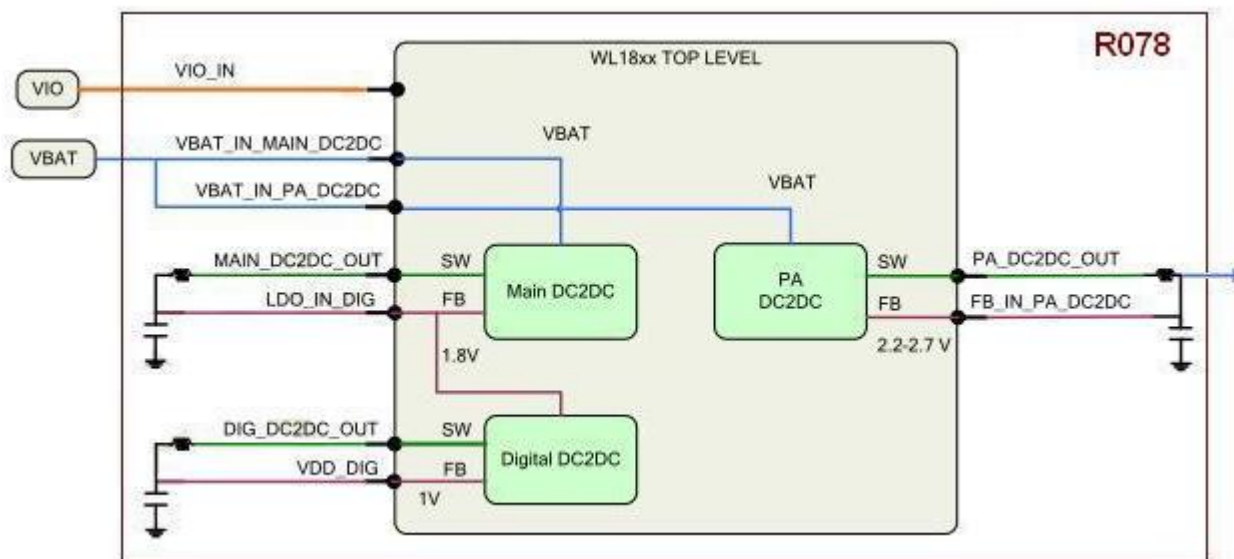


Figure 3-3 Internal DC2DC's

3.2.4 Reset / Power up system

After Vbat and VIO are fed to Device and while WLAN_EN are de-asserted (LOW), the device is in Shutdown state.

While in Shutdown state all functional blocks, internal DC2DC's and LDO's will be disabled. The power supplied to the functional blocks is cut off.

When one of the two signals WLAN_EN are asserted (High) a Power On Reset (POR) is performed.

Stable Slow Clock, VIO and Vbat are pre-requisites for successful POR.

3.2.4.1 Chip Top-level Power Up Sequence

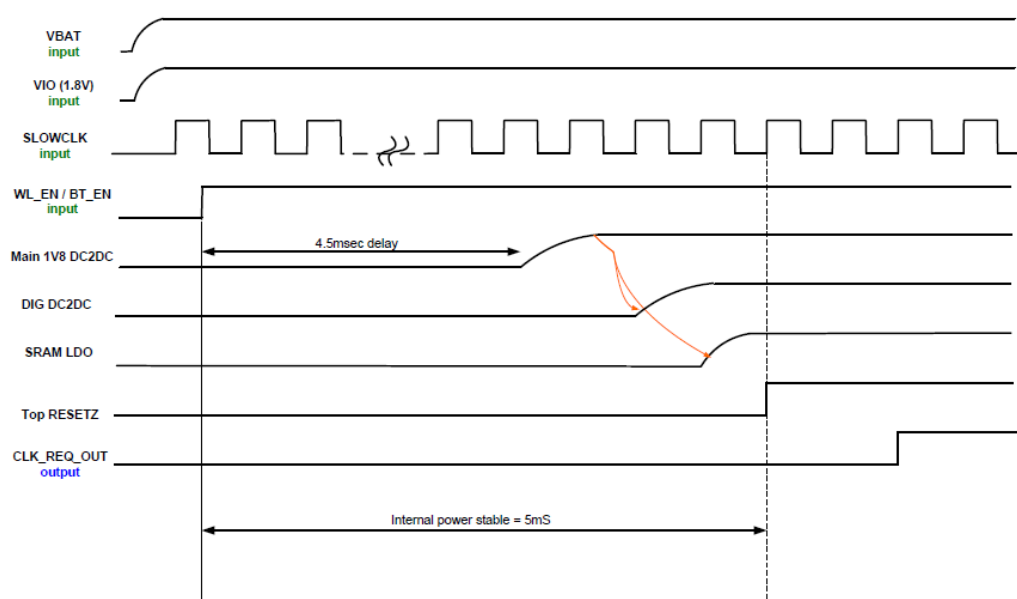


Figure 3-4 Chip Top-level Power Up Sequence

3.2.4.2 WLAN Power Up Sequence

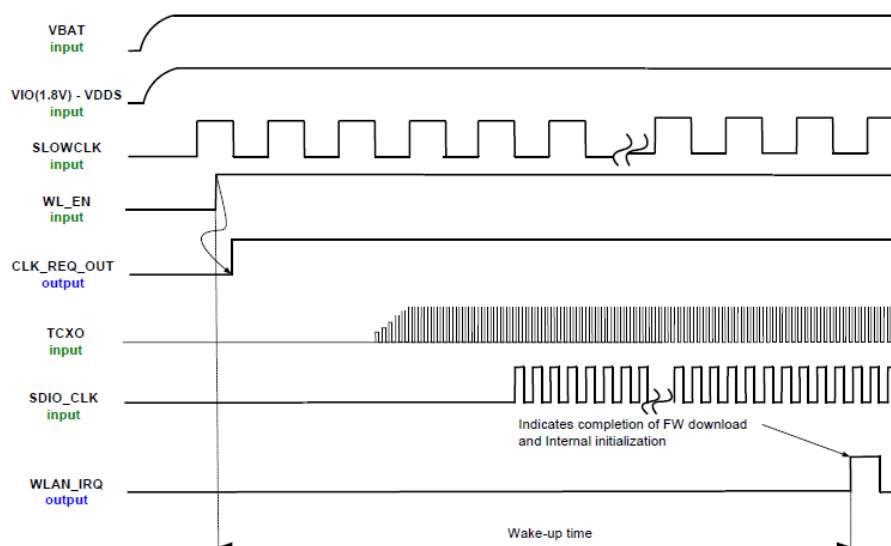


Figure 3-5 WLAN Power Up Sequence

3.3 WLAN Functional Block

3.3.1 WLAN MAC

R078 (WL1801) / D7021 MAC implements the IEEE standard 802.11 MAC sub-layer using both dedicated hardware and embedded firmware. The MAC hardware implements real-time functions, including access protocol management, encryption and decryption.

3.3.2 WLAN Baseband Processor

R078 (WL1801) / D7021 baseband processor implements the IEEE 802.11b/g/n PHY sub layers and has been optimized to perform well in conditions of high multipath and noise.

3.3.3 WLAN RF Radio

R078 (WL1801) / D7021 WLAN radio is a highly integrated radio processor designed for 802.11b/g/n applications, including internal front-end PA's.

3.3.4 WLAN RF Configuration and Power Options

The R078 (WL1801) / D7021 includes RF switch, band pass filter and diplexer for complete WLAN (SISO) RF system.

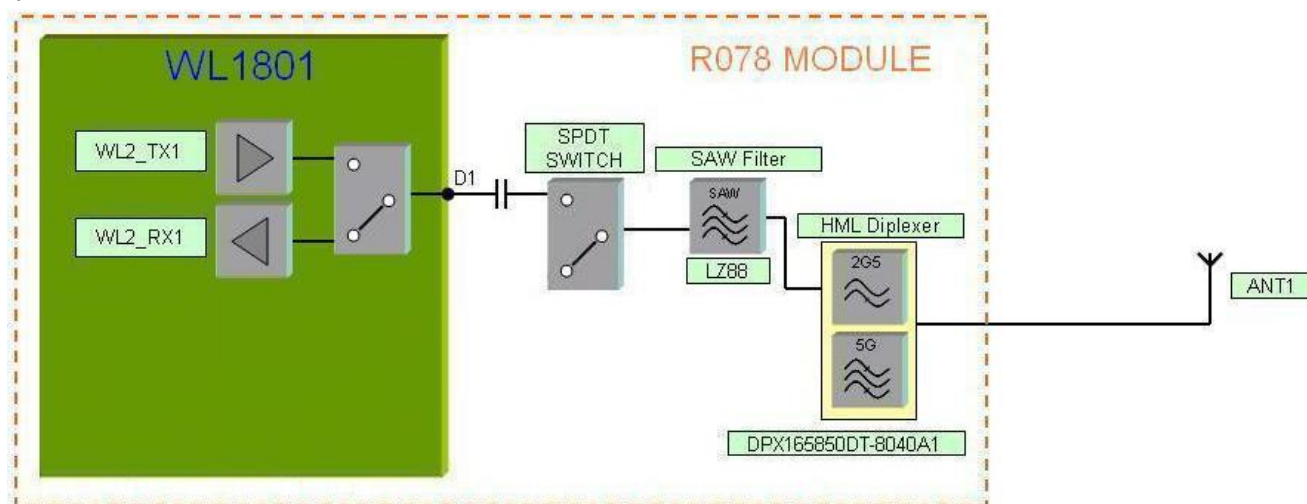


Figure 3-6 R078 (WL1801) / D7021 SISO configuration

3.3.4.1 SISO configuration (WL1801 device)

The diagram above shows WLAN pins in standard SISO application.

3.4 Terminal Assignments

The view is from top side:

	A	B	C	D	E	F	G	H	J	K	L	M	N	P	
12	GND	NU	GND	VIO	GND	GND	GND	GND	NU	NU	NU	NU	GND	GND	12
11	GND	NU	GND	GND	GND	SDIO_D2_WL	SDIO_CLK_WL	GND	NU	GND	NU	GND	GND	NU	11
10	GND	NU	GND	NU	GND	SDIO_D3_WL	SDIO_D0_WL	GND	DC2DC_REQ_MODE_SOC	CLK_REQ_OUT	GND	GND	GND	GND	10
9	GND	GND	GND	NU	GND	SDIO_CM_D_WL	SDIO_D1_WL	GND	SLOW_CLK	NU	NU	GND	GND	NU	9
8	NU	GND	NU	NU	GND	GND	GND	COEX_M_WS_BT_WL_TX_O	COEX_M_WS_FRAM_E_SYNC	NU	NU	GND	GND	NU	8
7	GND	GND	NU	GND	GND	COEX_M_WS_ACTI_VE	RX_SW_FEM_WL	COEX_M_WS_RX_P_RI	NU	NU	GND	GND	GND	NU	7
6	NU	GND	PBIAS_TESTP_W	GND	GND	DC2DC_REQ_OUT_SOC	WLAN_IR_Q	NU	GPIO_2	NU	NU	GND	GND	NU	6
5	GND	GND	PDET_TESTM_W	GND	GND	GND	WLAN_EN_SOC	FEM_PA_EN_WL	NU	GPIO_1	GND	GND	GND	GND	5
4	GND	GND	NU	GND	NU	NU	NU	NU	NU	GPIO_3	GND	VBAT1	VBAT2	VBAT3	4
3	11bg_ANT_1	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	GND	3
2	GND	GND	GND	GND	GND	CLK_IN_P	CLK_IN_M	GND	GND	GND	GND	GND	GND	GND	2
1	GND	GND	GND	GND	GND	GND	GND	GND	PA_DC2DC_IN	PA_DC2DC_OUT	GND	GND	GND	GND	1
	A	B	C	D	E	F	G	H	J	K	L	M	N	P	

	DIGITAL
	RF
	Power
	GND
	CLOCK
	DIGITAL High Speed
	Not Used

Top view

Figure 3-7 Terminal Assignments

3.5 Terminal Functions

Pin names and pin numbers in bracket apply to WSP pin out.

Table 3-3 Terminal Functions

Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)	I/O Type	Shut Down state	Default after POR	Buffer Type [mA]	Description
WLAN pins: I/O signals						
SDIO_CLK_WL (SDIO_CLK_WL)	G11 (E11)	IN	HiZ	HiZ		WLAN SDIO clock. Must be driven by the host.
SDIO_CMD_WL(SDIO_CMD_WL)	F9 (D8)	IN	HiZ	HiZ		WLAN SDIO command in. Host must pull up.
SDIO_D0_WL (SDIO_D0_WL)	G10 (E10)	I/O	HiZ	HiZ		WLAN SDIO data bit 0. Host must pull up.
SDIO_D1_WL (SDIO_D1_WL)	G9 (E9)	I/O	HiZ	HiZ		WLAN SDIO data bit 1. Host must pull up.
SDIO_D2_WL (SDIO_D2_WL)	F11 (D11)	I/O	HiZ	HiZ		WLAN SDIO data bit 2. Host must pull up.
SDIO_D3_WL (SDIO_D3_WL)	F10 (D10)	I/O	HiZ	PU		WLAN SDIO data bit 3. Changes state to PU at WL_EN assertion for card detect. Later disabled by the SW during init. Host must pull up.
WLAN_IRQ (IRQ_WL)	G6 (E3)	OUT	PD	Drive 0		SDIO available, interrupt out. Active high. To use WL_RS232_TX/RX lines, need to pull up with 10K resistor.
GPIO_1 (GPIO1)	K5 (H1)	I/O	PD	PD		Option: WL_RS232_TX (when IRQ_WL = 1 at power up)
GPIO_2 (GPIO2)	J6 (H2)	I/O	PD	PD		Option: WL_RS232_RX (when IRQ_WL = 1 at power up)
GPIO_3 (UART_DBG_WL)	K4 (G4)	OUT	PU	PU		WLAN logger Option: GPIO3
FEM_PA_EN_WL (GPIO13)	H5 (F2)					NC
RX_SW_FEM_WL (SW_CTRL_BG_IO1)	G7 (F3)					NC
PBIAS_TESTP_W (PBIAS_OUT_FEM_TESTP_WL)	C6 (C7)	ANA				NC
PDET_TESTM_W (PDET_IN_FEM_TESTM_WL)	C5 (C6)	ANA				NC
WLAN Pins: RF antenna						
11bg_ANT_1	A3	RF				WLAN BG RX and TX 50Ω input and output. No external matching required.
Clock pins						
CLK_IN_P	F2 (E4)	ANA				FREF/TCXO input for all functional blocks
CLK_IN_M	G2 (E5)	ANA				Connect to GND
SLOW_CLK (RTC_CLK)	J9 (H8)	ANA				Sleep clock 32.768 kHz
CLK_REQ_OUT	K10 (K11)	OUT	PD	PD		Request external fast clock NC if not used.

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Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)	I/O Type	Shut Down state	Default after POR	Buffer Type [mA]	Description
Enable pins						
WLAN_EN_SOC (WLAN_EN)	G5 (E1)	IN	PD	PD		High = enable
Power management pins						
VBAT1	M4	POW				Battery voltage
VBAT2	N4	POW				Battery voltage
VBAT3	P4	POW				Battery voltage
VIO	D12	POW				1.8V I/O power supply
PA_DC2DC_IN	J1	POW				PA power supply input, with internal PA_DC2DC connect to pin PA_DC2DC_OUT K1.
PA_DC2DC_OUT	K1	POW				DC2DC output for PA supply, with internal PA_DC2DC connect to pin PA_DC2DC_IN J1.
DC2DC_REQ_OUT_SOC (NU)	F6 (D3)					NC
DC2DC_REQ_MODE_SOC (NU)	J10 (J10)					NC
Co-existence signals						
COEX_MWS_RX_PRI (COEX_MWS_UART_RX)	H7 (G5)		PU	PU		General purpose IO. NC if not used.
COEX_MWS_BT_WL_TX_O (COEX_MWS_UART_TX)	H8 (G7)		PU	PU		General purpose IO. NC if not used.
COEX_MWS_ACTIVE (COEX_MWS_PRE_TX)	F7 (G8)		PU	PU		General purpose IO. NC if not used.
COEX_MWS_FRAME_SYNC (COEX_MWS_FRAME_SYNC)	J8 (H7)		PU	PU		General purpose IO. NC if not used.
Not used pins						
NU	A6 (A4)					NC
NU	A8					NC
NU	B10 (G11)					NC
NU	B11 (G9)					NC
NU	B12 (H11)					NC
NU	C4 (F9)					NC
NU	C7 (F8)					NC
NU	C8 (F11)					NC
NU	D8 (F10)					NC
NU	D9 (E8)					NC
NU	D10 (B11)					NC
NU	E4 (E2)					NC
NU	F4 (E7)					NC
NU	G4 (F7)					NC
NU	H4 (G6)					NC
NU	H6 (G2)					NC
NU	J4 (F6)					NC
NU	J5 (H3)					NC
NU	J7 (H5)					NC

Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)	I/O Type	Shut Down state	Default after POR	Buffer Type [mA]	Description
NU	J5 (H3)					NC
NU	J7 (H5)					NC
NU	J11 (G10)					NC
NU	J12 (J8)					NC
NU	K6 (J4)					NC
NU	K7 (K4)					NC
NU	K8 (K5)					NC
NU	K9 (J7)					NC
NU	K12 (K8)					NC
NU	L6 (H6)					NC
NU	L8 (L7)					NC
NU	L9 (K7)					NC
NU	L11 (L11)					NC
NU	L12 (M10)					NC
NU	M12 (M9)					NC
NC	P6 (M7)					NC
NC	P7 (M5)					NC
NU	P8 (L5)					NC
NU	P9 (M6)					NC
NU	P11 (K6)					NC
Ground pins						
GND	A1	GND				
GND	A2	GND				
GND	A4	GND				
GND	A5	GND				
GND	A7	GND				
GND	A9	GND				
GND	A10	GND				
GND	A11	GND				
GND	A12	GND				
GND	B1	GND				
GND	B2	GND				
GND	B3	GND				
GND	B4	GND				
GND	B5	GND				
GND	B6	GND				
GND	B7	GND				
GND	B8	GND				
GND	B9	GND				

Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)	I/O Type	Shut Down state	Default after POR	Buffer Type [mA]	Description
GND	C1	GND				
GND	C2	GND				
GND	C3	GND				
GND	C9	GND				
GND	C10	GND				
GND	C11	GND				
GND	C12	GND				
GND	D1	GND				
GND	D2	GND				
GND	D3	GND				
GND	D4	GND				
GND	D5	GND				
GND	D6	GND				
GND	D7	GND				
GND	D11	GND				
GND	E1	GND				
GND	E2	GND				
GND	E3	GND				
GND	E5	GND				
GND	E6	GND				
GND	E7	GND				
GND	E8	GND				
GND	E9	GND				
GND	E10	GND				
GND	E11	GND				
GND	E12	GND				
GND	F1	GND				
GND	F3	GND				
GND	F5	GND				
GND	F8	GND				
GND	F12	GND				
GND	G1	GND				
GND	G3	GND				
GND	G8	GND				
GND	G12	GND				
GND	H1	GND				
GND	H2	GND				
GND	H3	GND				
GND	H9	GND				

Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)	I/O Type	Shut Down state	Default after POR	Buffer Type [mA]	Description
GND	H10	GND				
GND	H11	GND				
GND	H12	GND				
GND	J2	GND				
GND	J3	GND				
GND	K2	GND				
GND	K3	GND				
GND	K11	GND				
GND	L1	GND				
GND	L2	GND				
GND	L3	GND				
GND	L4	GND				
GND	L5	GND				
GND	L7	GND				
GND	L10	GND				
GND	M1	GND				
GND	M2	GND				
GND	M3	GND				
GND	M5	GND				
GND	M6	GND				
GND	M7	GND				
GND	M8	GND				
GND	M9	GND				
GND	M10	GND				
GND	M11	GND				
GND	N1	GND				
GND	N2	GND				
GND	N3	GND				
GND	N5	GND				
GND	N6	GND				
GND	N7	GND				
GND	N8	GND				
GND	N9	GND				
GND	N10	GND				
GND	N11	GND				
GND	N12	GND				
GND	P1	GND				
GND	P2	GND				
GND	P3	GND				

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Module Pin Name (WSP Pin Name)	Module Pin No. (WSP ball no.)	I/O Type	Shut Down state	Default after POR	Buffer Type [mA]	Description
GND	P5	GND				
GND	P10	GND				
GND	P12	GND				

4 Design Goal Specifications

Section Disclaimer

This Specification is based upon the Texas Instruments WL180x Data Sheet version 1.2, and is subject to any subsequent changes in applicable Texas Instruments documentation and software.

Any parameter marked TBD indicates that this is yet to be determined by TDK design/testing. Any parameter marked TBC indicates that this is yet to be determined in an update of Texas Instruments documentation.

4.1 General Chip Requirements and Operation

All parameters are measured as follows unless stated otherwise: VIO=1.8V

4.1.1 Absolute Maximum Ratings ⁽¹⁾

			Value	Unit
VBAT ⁽²⁾			-0.5 to 5.5 ⁽⁴⁾	V
VIO			-0.5 to 2.1	V
Input voltage to Analog pins ⁽³⁾			-0.5 to 2.1	V
Input voltage to all other pins			-0.5 to (VDD_IO + 0.5V)	V
Operating ambient temperature range			-30 to +85 ⁽⁵⁾	°C
ESD Stress Voltage ⁽⁶⁾	Human Body Model ⁽⁷⁾	RF pins	>500	V
		Other	>1000	V
	Charged Device Model ⁽⁸⁾	RF pins	>300	V
		Other	>250	V

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The following signals are from the VBAT group: VBAT1, VBAT2, VBAT3

(3) Analog pins: 11bg_ANT_1.

(4) 5.5V up to 10s cumulative in 7 years. 5V cumulative to 250s, 4.8V cumulative to 2.33 years – all includes charging dips and peaks.

(5) Operating free-air temperature range. The device can be reliably operated for 7 years at T_{ambient} of 85°C, assuming 25% active mode and 75% sleep mode (15,400 cumulative active power-on hours).

(6) Electrostatic discharge (ESD) to measure device sensitivity/immunity to damage caused by electrostatic discharges into the device.

(7) Level listed is the passing level per ANSI/ESDA/JEDEC JS-001. JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process, and manufacturing with less than 500V HBM is possible if necessary precautions are taken. Pins listed as 1000V may actually have higher performance.

(8) Level listed is the passing level per EIA-JEDEC JESD22-C101E. JEDEC document JEP157 states that 250 V CDM allows safe manufacturing with a standard ESD control process, and manufacturing with less than 250V CDM is possible if necessary precautions are taken. Pins listed as 250 V may actually have higher performance.

4.1.2 Recommended Operating Conditions

Rating	Condition	Sym	Min	Max	Unit
1.8V core supply voltage			1.7	1.95	V
Vbat	DC supply range for all modes		3.4	4.3	
IO high-level input voltage		VIH	0.65 x VDD_IO	VDD_IO	
IO low-level input voltage		VIL	0	0.35 x VDD_IO	
Enable inputs high-level input voltage		Vih_en	1.365	VDD_IO	
Enable inputs low-level input voltage		Vil_en	0	0.4	
High-level output voltage	@4 mA	VOH	VDD_IO – 0.45	VDD_IO	
	@ 1 mA		VDD_IO – 0.112	VDD_IO	
	@0.3 mA		VDD_IO- 0.033	VDD_IO	
Low-level output voltage	@4 mA	VOL	0	0.45	
	@ 1 mA		0	0.112	
	@0.09 mA		0	0.01	
Input transitions time Tr/Tf from 10% to 90% (Digital IO) ⁽¹⁾		Tr/Tf	1	10	ns
Output rise time from 10% to 90% (Digital pins) ⁽¹⁾	CL <25 pF	Tr		5.3	ns
Output fall time from 10% to 90% (Digital pins) ⁽¹⁾	CL <25 pF	Tf		4.9	
Ambient operating temperature			-30	+85	°C

(1) Applies to all Digital lines except SDIO, SPI, UART, I2C, PCM and slow clock lines

4.1.3 External Digital Slow Clock Requirements (-30°C to +85°C)

The supported digital slow clock is 32.768 kHz digital (square wave). All core functions share a single input.

Characteristics	Condition	Sym	Min	Typ	Max	Unit
Input slow clock frequency				32768		Hz
Input slow clock accuracy (initial + temp + aging)	WLAN, BT				±250	ppm
Input transition time Tr/Tf -IO% to 90%		Tr/Tf			100	ns
Frequency input duty cycle			15	50	85	%
Input voltage limits	Square wave, DC-coupled	Vih	0.65xVDD_IO		VDD_IO	Vpeak
		Vil	0		0.35xVDD_IO	
Input impedance			1			MΩ
Input capacitance					5	pF

4.1.4 External fast clock Crystal Requirements and operation (-30°C to +85°C)

Characteristics	Condition	Min	Typ	Max	Unit
Supported frequencies		26, 38.4			MHz
Frequency accuracy	Initial + temp + aging			±20	ppm
Load capacitance, $C_L^{(1)}$		5		13	pF
Equivalent Series Resistance, ESR				60	ohms
Drive level			100		uW

1) Load capacitance, $CL = [C1.C2] / [C1 + C2] + CP$, where C1, C2 are the capacitors connected on CLK_IN_P & CLK_IN_M respectively and CP is the parasitic capacitance (typically 1-2pF).

For example, for C1 = C2 = 12pF and CP = 2pF, then CL = 8pF.

4.1.5 External TCXO CLK Requirements (-30°C to +85°C)

Parameter	Conditions	Min	Typ	Max	Unit
Supported frequency		26, 38.4			MHz
Frequency accuracy	Total short and long term			±20	ppm
Input voltage limits (TCXO_P)	Sine wave/	2.4GHz WLAN	0.2	1.4	Vp-p
	ac-coupled	5GHz WLAN	0.8	1.4	
Input impedance, 26 MHz	RP	Input resistance	20		kΩ
	CP	Input capacitance		2.5	pF
Input impedance, 38.4 MHz	RP	Input resistance	15		kΩ
	CP	Input capacitance		2.5	pF
Power-up time ⁽¹⁾				5	ms
Phase noise 2.4GHz for 38.4MHz 20MHz SISO ⁽²⁾	Measured at 1 KHz offset			-120	dBc/Hz
	Measured at 10 KHz offset			-130	dBc/Hz
	Measured at 100 KHz offset			-135	dBc/Hz
Phase noise 2.4GHz for 38.4MHz 40MHz SISO ⁽²⁾	Measured at 1 KHz offset			-125	dBc/Hz
	Measured at 10 KHz offset			-132	dBc/Hz
	Measured at 100KHz offset			-136.5	dBc/Hz
Phase noise 5GHz for 38.4MHz, 20/40MHz SISO ⁽²⁾	Measured at 1 KHz offset			-125	dBc/Hz
	Measured at 10 KHz offset			-142	dBc/Hz
	Measured at 100KHz offset			-145	dBc/Hz

(1) Power-up time is calculated from the time CLK_REQ_OUT asserted till the time the TCXO_CLK amplitude is within voltage limit specified above and TCXO_CLK frequency is within ±0.1 ppm of final steady state frequency.

(2) The phase noise numbers listed here must be met at 38.4 MHz. For other frequencies the phase noise requirement is corrected by adding $20 \times \log_{10}(f_{TCXO} / 38.4e6)$ dB. Specifically, for 26 MHz TCXO, the correction factor would be -3.4 dB.

* The slope of the clock at zero-crossings should not be less than that of a 200 mVp-p sine-wave . i.e. 26MHz clock: 16V/μs (for 11bg band) 38.4MHz clock: 24V/μs (for 11bg band)

4.2 WLAN RF Performance

All specifications in this draft data sheet are design goal level and subject to change. All specifications have been measured using TDK CB (Carrier Board) and are given at the module pins (Carrier Board insertion loss is de-embedded). All measurements have been performed over VBAT voltage range from 3.4V to 4.3V and over temperature range from -30°C to +85°C.

* 11n 40MHz bandwidth function is available. However the RF performance is guaranteed by only WL180x.

4.2.1 WLAN 2.4 GHz Radio Characteristics

4.2.1.1 WLAN 2.4 GHz Receiver RF Characteristics

Characteristics	Condition	Min	Typ	Max	Unit
Operation frequency range		2400		2480	MHz
Sensitivity (ANT1)	1 Mbps DSSS			-91	dBm
20MHz bandwidth.	54 Mbps OFDM			-70	
At < 10% PER limit	MCS7			-65	
Max Input Level	OFDM (11g/n)	-19			dBm
At < 10% PER limit	CCK	-4			
Adjacent Channel Rejection at sensitivity level +3 for OFDM and +6 for CCK	2Mbps	42.7			dB
	11 Mbps	37.9			
	54 Mbps	2			
LO leakage			-80		dBm

4.2.1.2 WLAN 2.4 GHz Receiver Blocking Characteristics Per Band

The R078 (WL1801) / D7021 is designed to coexist with co-located cellular transmitters. Table below lists typical cellular interference sources and the corresponding maximum power from the cellular interference source that can be present at the input terminal of R078 (WL1831) / D7021, such that WLAN receiver sensitivity is not degraded by more than 1 dB. (Further improvement is achieved by antenna isolation)

Characteristics	Condition	Min	Typ	Max	Unit
Blocking performance at other bands	776 to 794 MHz (CDMA)	+10			dBm
	824 to 849 MHz (GMSK)	+10			
	824 to 849 MHz (EDGE)	+10			
	824 to 849 MHz (CDMA)	+10			
	880 to 915 MHz (GMSK)	+21			
	880 to 915 MHz (EDGE)	+21			
	1710 to 1785 MHz (GMSK)	+3			
	1710 to 1785 MHz (EDGE)	+3			
	1850 to 1910 MHz (GMSK)	-3			
	1850 to 1910 MHz (EDGE)	-3			
	1850 to 1910 MHz (CDMA)	-10			
	1850 to 1910 MHz (WCDMA)	-10			
	1920 to 1980 MHz (WCDMA)	-10			

4.2.1.3 WLAN 2.4 GHz Transmitter power

RF transmission (Tx) tests are done in continuous transmission.

Characteristics	Condition	11bg_ANT_1 pin		
		Min	Typ	Max
Maximum output power	1 Mbps	+12	+15	
	11Mbps	+12	+15	
	6 Mbps at EVM: -10 dB,	+10	+13	
	54 Mbps at EVM: -25 dB	+9	+12	
	MCS0 (Greenfield) at EVM: -10 dB	+9	+13	
	MCS7 (Greenfield) at EVM: -28 dB	+8	+11	
Output power accuracy			± 1.5	
Transmit power control resolution			0.125	

4.2.1.4 WLAN 2.4 GHz Transmitter out-of-band emissions

Table below shows 2.4GHz WLAN transmitter out-of-band emissions for each band listed in the Condition column. The wideband noise at 2.4GHz WLAN antenna port is also listed.

Characteristics	Condition	Min	Typ	Max	Unit
Cellular bands out-of-band broadband emissions(1)	746 to 764 MHz (CDMA1)			-145	dBm/Hz
	869 to 894 MHz (GSM850)			-145	
	925 to 960 MHz (EGSM900)			-138	
	1570 to 1580 MHz (GPS)			-142	
	1596 to 1609 MHz (GLONASS)			-130	
	1805 to 1880 MHz (DCS1800)			-140	
	1930 to 1990 MHz (PCS1900)			-120	
	2110 to 2170 MHz			-129	
Cellular bands out-of-band spurious emissions	746 to 764 MHz (CDMA)			-44.2 ⁽⁴⁾	dBm
	869 to 894 MHz (CDMA, GSM850)			-44.2 ⁽⁴⁾	
	925 to 960 MHz (EGSM900)			-44.2 ⁽⁴⁾	
	1570 to 1580 MHz (GPS)			-44.2 ⁽⁴⁾	
	1805 to 1880 MHz (DCS1800)			-44.2 ⁽⁴⁾	
	1930 to 1990 MHz (PCS1900, CDMA)			-44.2 ⁽⁴⁾	
	2110 to 2170 MHz			-44.2 ⁽⁴⁾	
Spurious emission during operation at 1MHz RBW	30MHz – 1GHz			-55 ⁽²⁾	dBm
	2 nd harmonic			-33 ⁽³⁾	
	3 rd harmonic			-33 ⁽³⁾	
	4 th harmonic			-33 ⁽³⁾	
	5 th harmonic			-33 ⁽³⁾	

(1) Figures are for max transmission power for all available modulations. The setup noise floor is -167dBm/Hz.

(2) Based on TI IC performance

(3) ETSI limit plus 3dB margin

(4) FCC conductive limit plus 3dB margin

4.2.1.5 2.4GHz WLAN Current Consumption

Active Current				
Spec item ⁽¹⁾	MIN	TYP	MAX	Units
Tx 11CCK @15dBm		345	380	mA
Tx 54OFDM @12dBm		290	320	mA
Rx		65	75	mA

(1) All measured at ANT1 and the 3.6V VBAT rail of the solution. TCXO current included.

4.3 Interface Timing Characteristics

4.3.1 SDIO timing specifications

4.3.1.1 SDIO Switching Characteristics – Default rate input and output

Specification is over recommended operating conditions. Parameters are for default clock frequency.

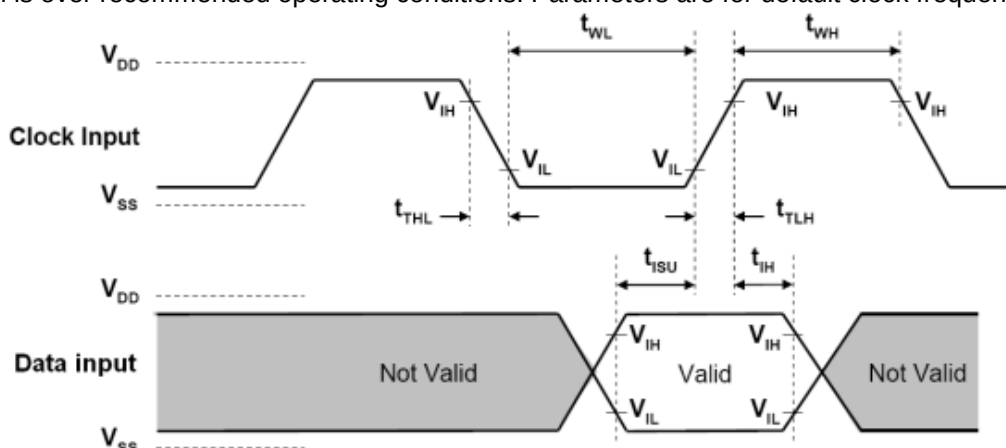


Figure 4-1 SDIO default input timing

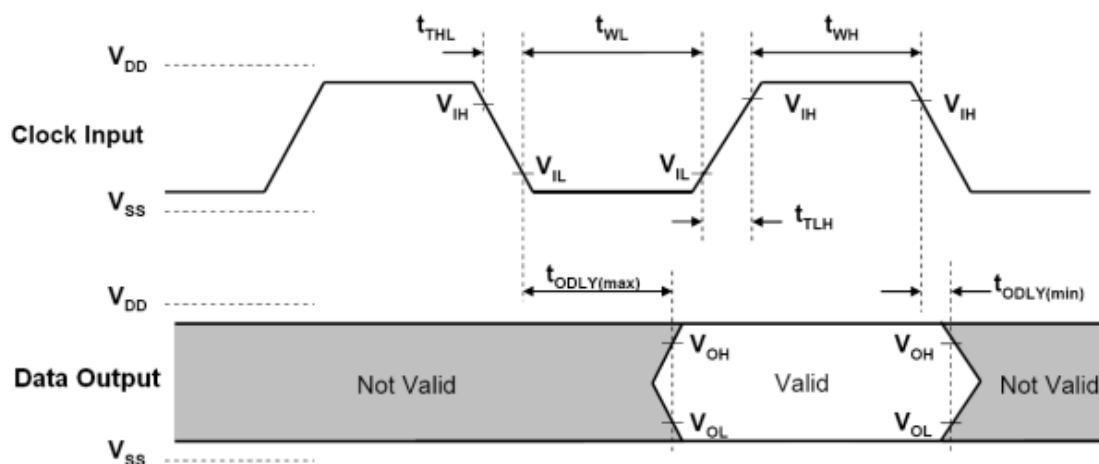


Figure 4-2 SDIO default output timing

Table 4-1 SDIO Switching Characteristics – Default Rate

Parameter		Min	Max	Unit
f_{clock}	Clock frequency, CLK	0	26	MHz
DC	Low/high duty cycle	40	60	%
t_{TLH}	Rise time, CLK		10	ns
t_{THL}	Fall time, CLK		10	ns
t_{ISU}	Setup time, input valid before CLK $\uparrow$	3		ns
t_{IH}	Hold time, input valid after CLK $\uparrow$	2		ns
t_{ODLY}	Delay time, CLK $\downarrow$ to output valid	2.5	14.8	ns
CI	Capacitive load on outputs		15	pF

Note: Option to change data out clock edge from falling edge (default) to rising edge, by setting configuration bit.

4.3.1.2 SDIO Switching Characteristics – High Rate

Specification is over recommended operating conditions. Parameters are for maximum clock frequency.

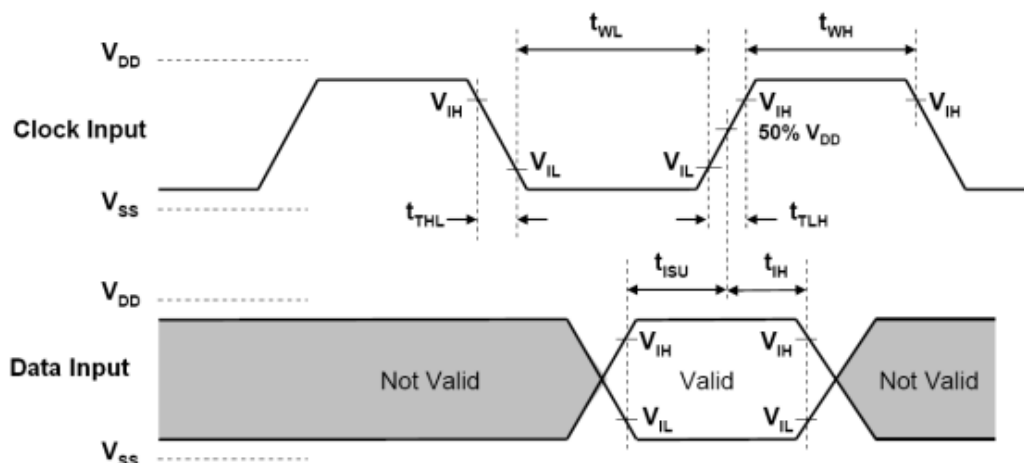


Figure 4-3 SDIO HS input timing

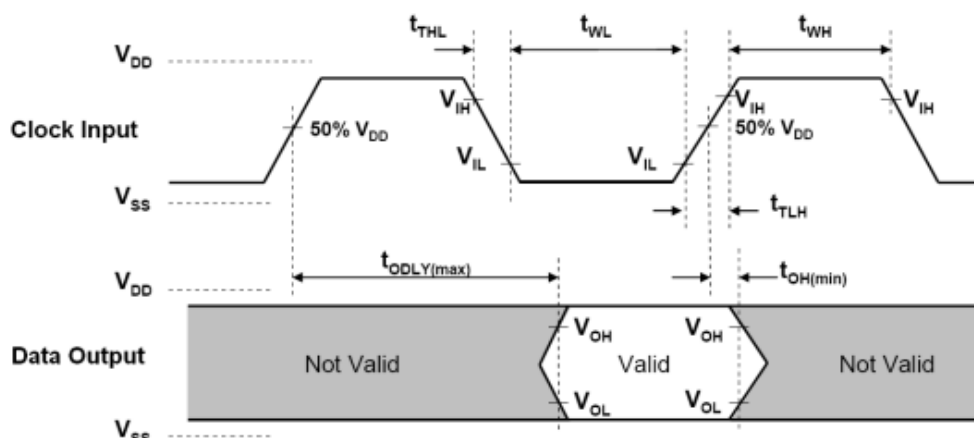


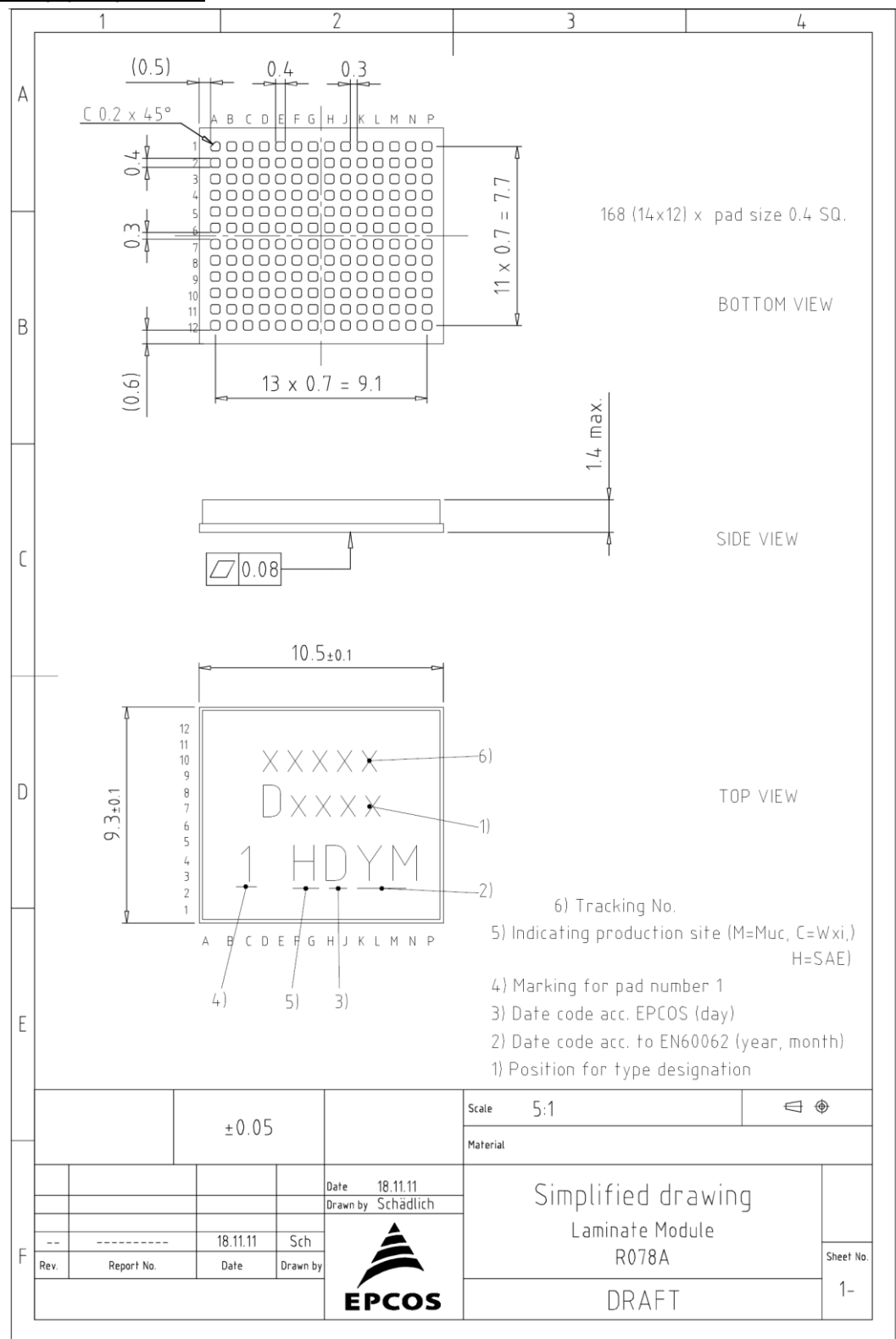
Figure 4-4 SDIO HS output timing

Table 4-2 SDIO Switching Characteristics – High Rate

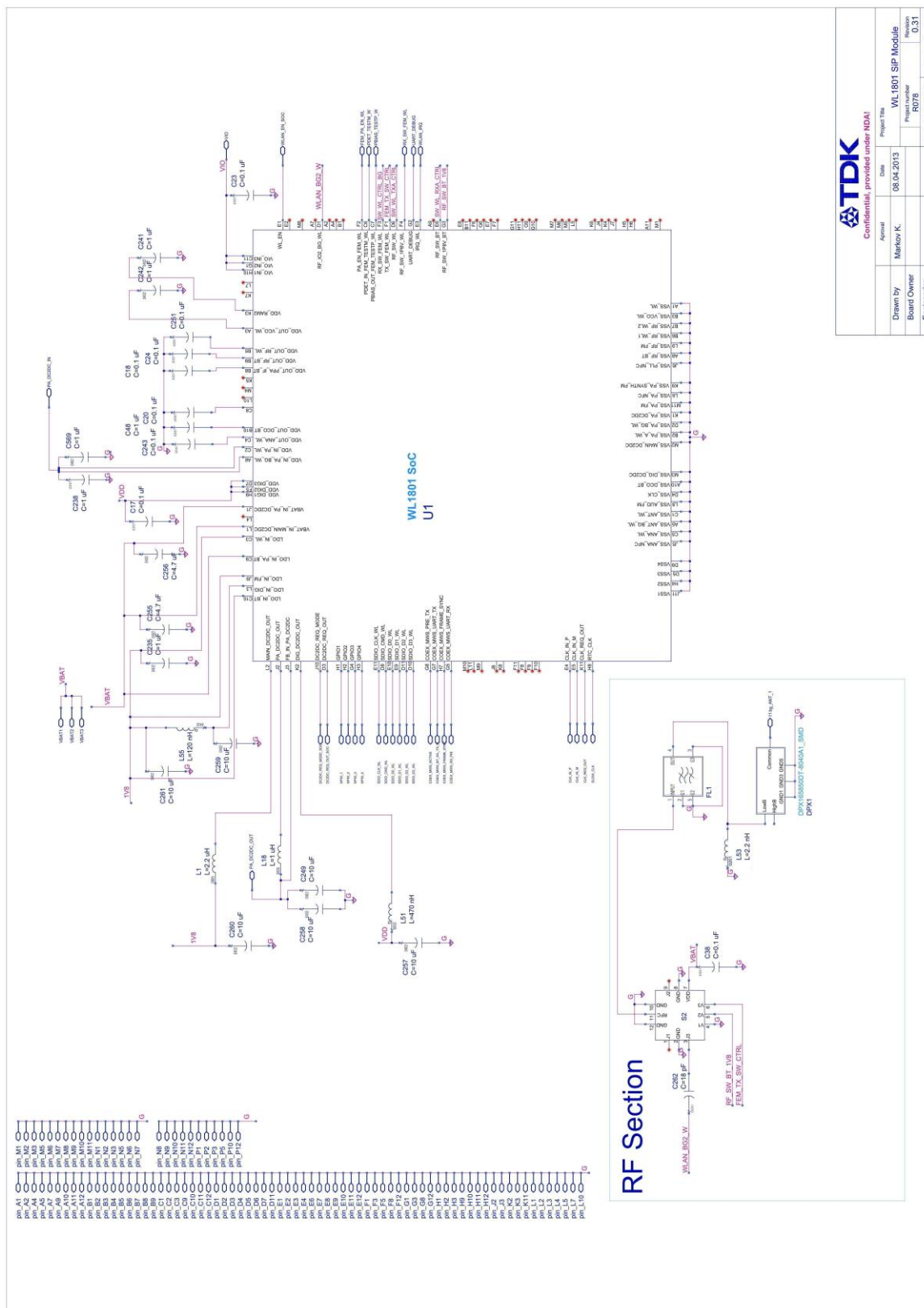
Parameter		Min	Max	Unit
f _{clock}	Clock frequency, CLK	0	50	MHz
DC	Low/high duty cycle	40%	60%	
t _{TLH}	Rise time, CLK		3	ns
t _{THL}	Fall time, CLK		3	ns
t _{ISU}	Setup time, input valid before CLK ↑	3		ns
t _{IH}	Hold time, input valid after CLK ↑	2		ns
t _{ODLY}	Delay time, CLK ↓ to output valid	2.5	14	ns
CI	Capacitive load on outputs		10	pF

4.4 Package Mechanical Drawing

Land Grid Array (LGA) Module



4.5 Schematic



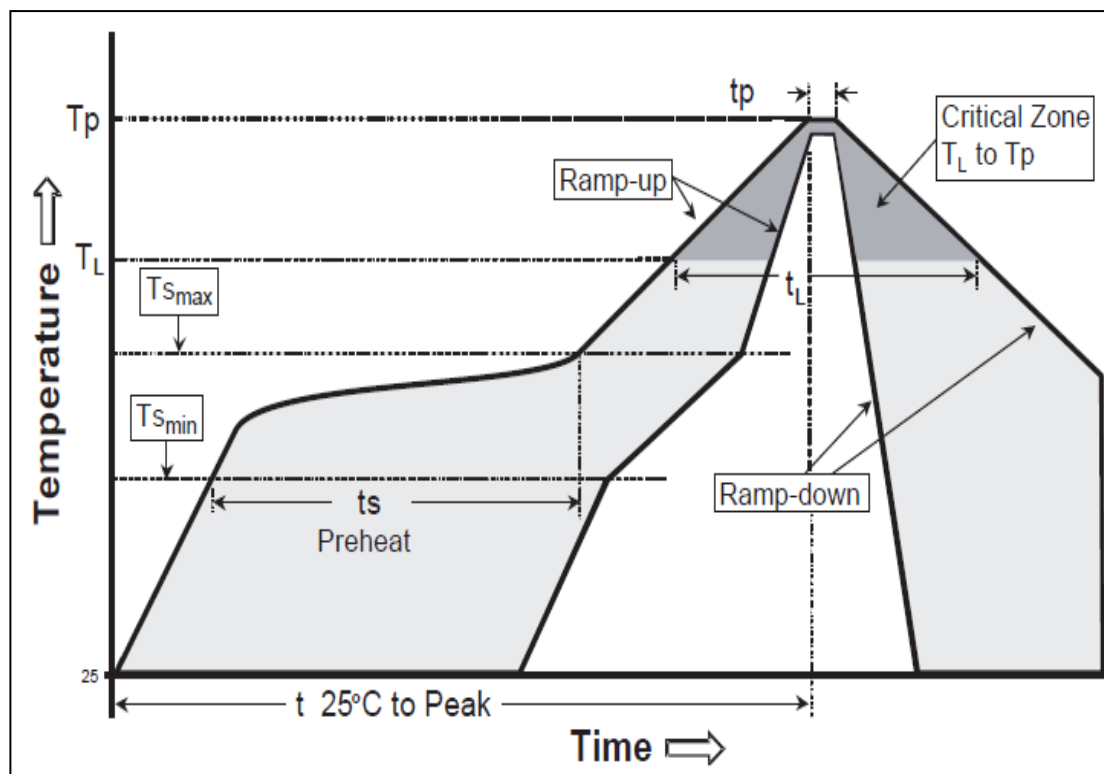
TDK Confidential, provided under NDA		Project Title	WL1801 SiP Module
Drawn by	Markov K.	Date	06.04.2013
Board Owner	Engineering	Project Number	R078
		Revision	0.31
		Date	06.04.2013
		Sheet	01 of 01

5 Lead-free Product Status

All Epcos modules in mass production are lead-free. This is achieved by using only materials with lead contamination below 1000 ppm. The applied lead-free solder alloy is the main source of Pb-contamination, which together gives Pb-levels much below 50 ppm per module.

A comprehensive qualification for these lead-free module packages has been done. The related AQTP documentation is available from Epcos on request.

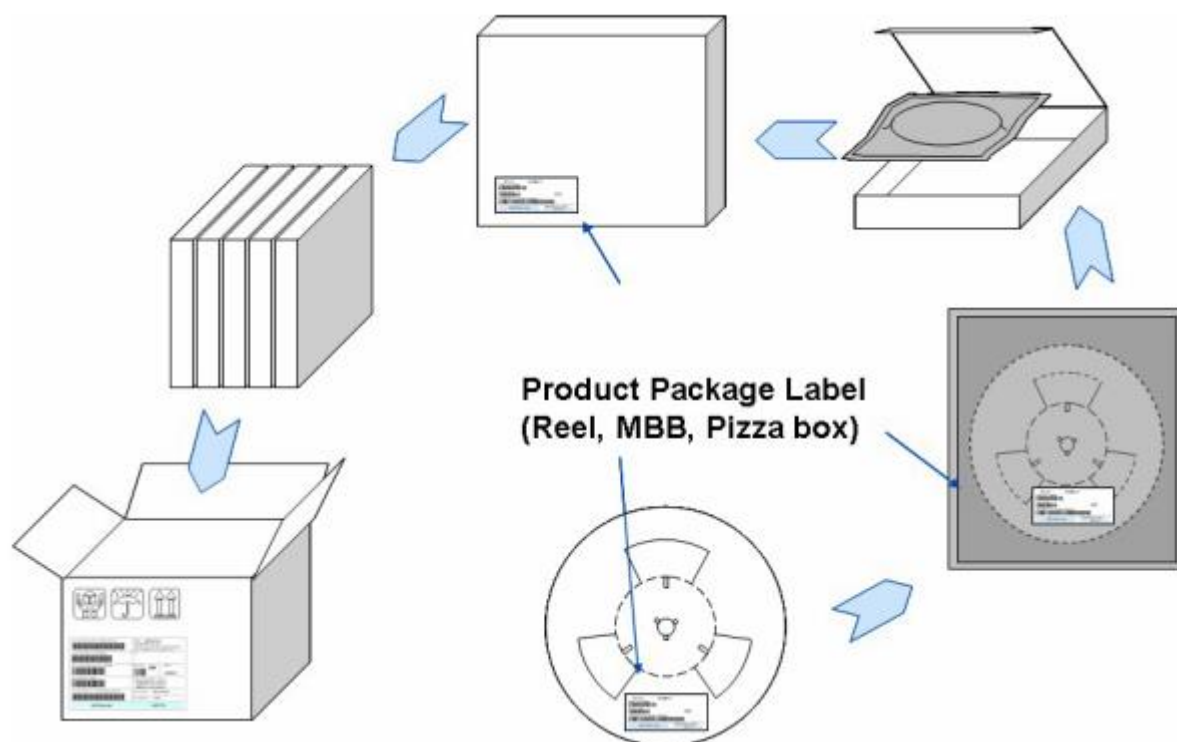
6 Recommended Reflow Profile



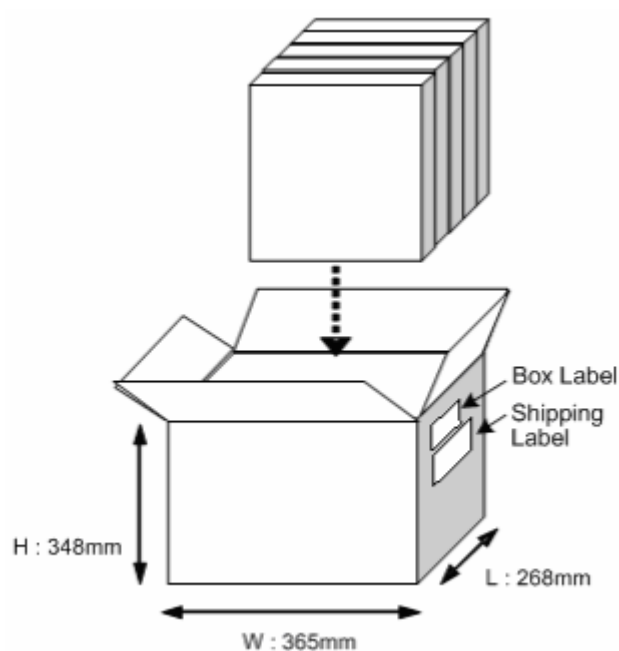
Profile Feature	Range
Average Ramp-Up Rate ($T_{s_{max}}$ to T_p)	3°C/second max.
Preheat: -Temperature Min ($T_{s_{min}}$) -Temperature Max ($T_{s_{max}}$) -Time ($t_{s_{min}}$ to $t_{s_{max}}$)	150°C 200°C 60-120 seconds
Time maintained above: -Temperature (T_L) -Time (t_L)	217°C 60-150 seconds
Peak Temperature (T_p)	245-250°C
Time within 5°C of actual Peak Temperature (T_p)	20-40 seconds
Ramp-Down Rate	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

7 Packing Information

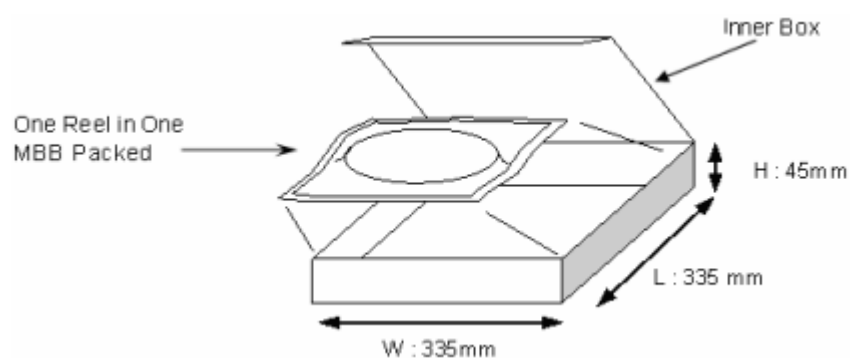
7.1.1 Packaging flow



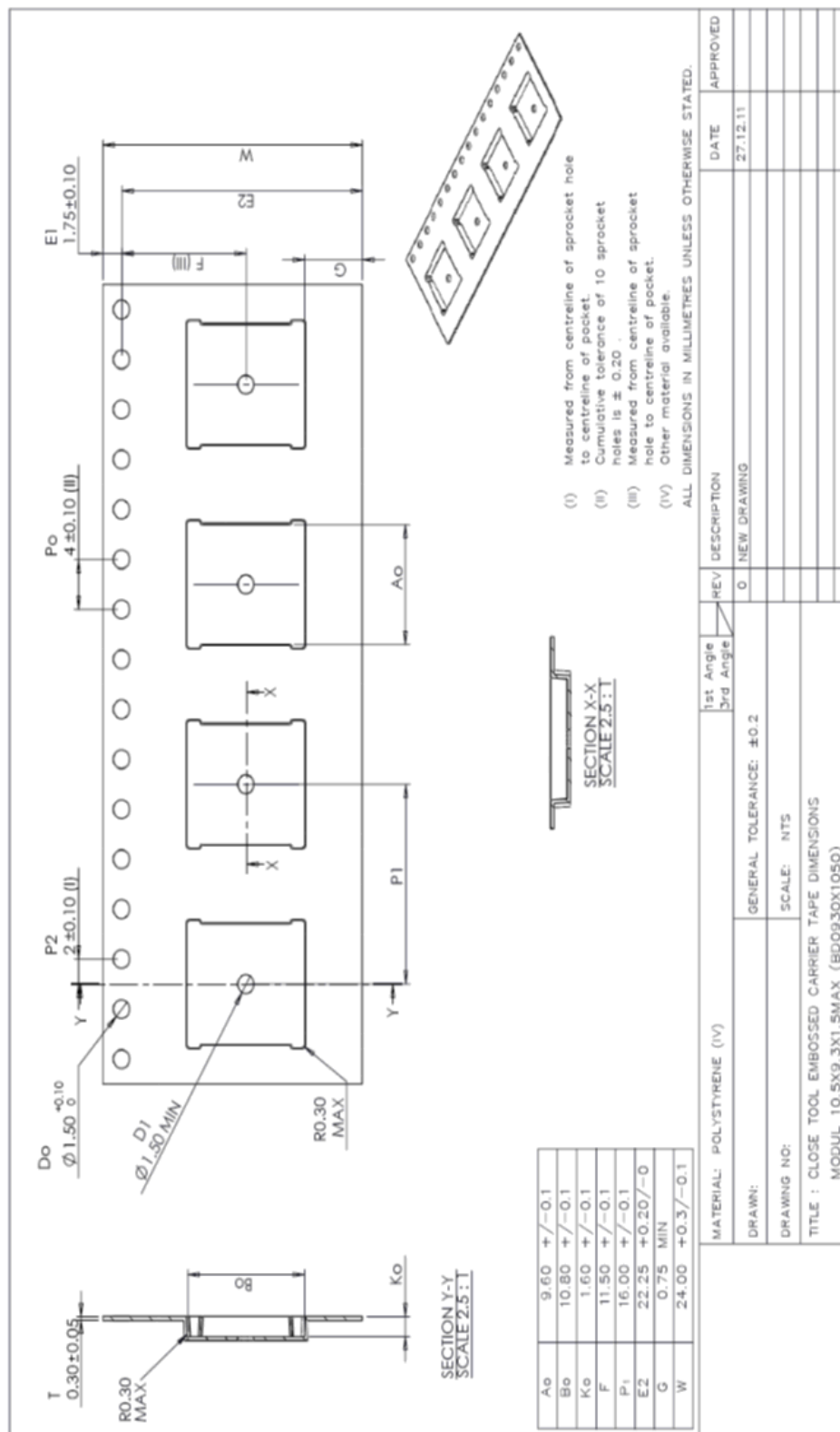
7.1.2 Outer Box



7.1.3 Inner Box



7.1.4 Tape drawing



8 Revision History

Version	Date	Status	Note
1.0	27.6.2014	Official Release	Initial
1.1	3.9.2014	Official Release	Changed 4.1.1 Absolute Maximum Ratings Operating ambient temperature range : -15 to +55 °C
1.2	25.9.2014	Official Release	Changed the template of the data sheet Updated operation temperature range : -30 to +85°C Updated 4.2.1.3 WLAN 2.4 GHz Transmitter power (1Mbps and 11Mbps)

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